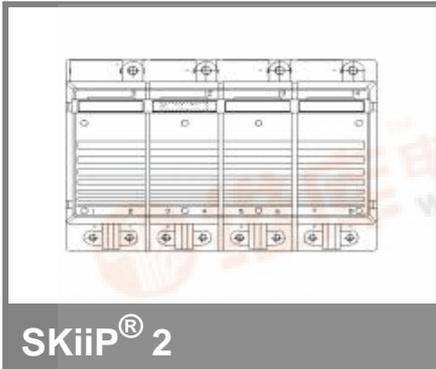


# SKiiP 832GB120-4D



## 2-pack - integrated intelligent Power System

### Power section

#### SKiiP 832GB120-4D

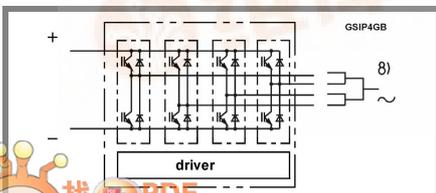
### Features

- SKiiP technology inside
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 2 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532

- 1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- 8) AC connection busbars must be connected by the user; copper busbars available on request

| Absolute Maximum Ratings |   | $T_s = 25^\circ\text{C}$ unless otherwise specified |                       |
|--------------------------|---|---|-----------------------|
| Symbol                   | Conditions                                      | Values  | Units                 |
| <b>IGBT</b>              |   |   |                       |
| $V_{CES}$                | Operating DC link voltage                       | 1200  | V                     |
| $V_{CC}^{(1)}$           |   | 900   | V                     |
| $V_{GES}$                |   | $\pm 20$  | V                     |
| $I_C$                    | $T_s = 25 (70)^\circ\text{C}$                   | 800 (600)   | A                     |
| <b>Inverse diode</b>     |   |   |                       |
| $I_F = -I_C$             | $T_s = 25 (70)^\circ\text{C}$                   | 800 (600)   | A                     |
| $I_{FSM}$                | $T_j = 150^\circ\text{C}$ , $t_p = 10$ ms; sin. | 5760  | A                     |
| $I^2t$ (Diode)           | Diode, $T_j = 150^\circ\text{C}$ , 10 ms        | 166   | $\text{kA}^2\text{s}$ |
| $T_j, (T_{stg})$         |   | - 40 (- 25) ... + 150 (125)                         | $^\circ\text{C}$      |
| $V_{isol}$               | AC, 1 min. (mainterminals to heat sink)         | 3000  | V                     |

| Characteristics   |   | $T_s = 25^\circ\text{C}$ unless otherwise specified |           |                |                  |     |      |       |      |
|---|---|---|-----------|----------------|------------------|-----|------|-------|------|
| Symbol  | Conditions  | min.  | typ.      | max.           | Units            |     |      |       |      |
| <b>IGBT</b>   |   |   |           |                |                  |     |      |       |      |
| $V_{CEsat}$   | $I_C = 700$ A, $T_j = 25 (125)^\circ\text{C}$                                   |   | 2,6 (3,1) | 3,1            | V                |     |      |       |      |
| $V_{CEO}$   | $T_j = 25 (125)^\circ\text{C}$  |   | 1,2 (1,3) | 1,5 (1,6)      | V                |     |      |       |      |
| $r_{CE}$  | $T_j = 25 (125)^\circ\text{C}$  |   | 1,9 (2,5) | 2,3 (2,9)      | $\text{m}\Omega$ |     |      |       |      |
| $I_{CES}$   | $V_{GE} = 0$ V, $V_{CE} = V_{CES}$ ,<br>$T_j = 25 (125)^\circ\text{C}$          |   | (40)      | 1,6            | mA               |     |      |       |      |
| $E_{on} + E_{off}$  | $I_C = 700$ A, $V_{CC} = 600$ V<br>$T_j = 125^\circ\text{C}$ , $V_{CC} = 900$ V |   |           | 210<br>370     | mJ<br>mJ         |     |      |       |      |
| $R_{CC'} + EE'$   | terminal chip, $T_j = 125^\circ\text{C}$  |   | 0,13      |                | $\text{m}\Omega$ |     |      |       |      |
| $L_{CE}$  | top, bottom   |   | 3,8       |                | nH               |     |      |       |      |
| $C_{CHC}$   | per phase, AC-side  |   | 5,6       |                | nF               |     |      |       |      |
| <b>Inverse diode</b>  |   |   |           |                |                  |     |      |       |      |
| $V_F = V_{EC}$  | $I_F = 600$ A, $T_j = 25 (125)^\circ\text{C}$                                   |   | 2,1 (1,9) | 2,6            | V                |     |      |       |      |
| $V_{TO}$  | $T_j = 25 (125)^\circ\text{C}$  |   | 1,3 (1)   | 1,4 (1,1)      | V                |     |      |       |      |
| $r_T$   | $T_j = 25 (125)^\circ\text{C}$  |   | 1,3 (1,5) | 1,7 (2)        | $\text{m}\Omega$ |     |      |       |      |
| $E_{rr}$  | $I_C = 700$ A, $V_{CC} = 600$ V<br>$T_j = 125^\circ\text{C}$ , $V_{CC} = 900$ V |   |           | 24<br>31       | mJ<br>mJ         |     |      |       |      |
| <b>Mechanical data</b>  |   |   |           |                |                  |     |      |       |      |
| $M_{dc}$  | DC terminals, SI Units  | 6   |           | 8              | Nm               |     |      |       |      |
| $M_{ac}$  | AC terminals, SI Units  | 13  |           | 15             | Nm               |     |      |       |      |
| w   | SKiiP® 2 System w/o heat sink   |   | 3,5       |                | kg               |     |      |       |      |
| w   | heat sink   |   | 8,5       |                | kg               |     |      |       |      |
| <b>Thermal characteristics (P16 heat sink; 275m<sup>3</sup>/h); "r" reference to temperature sensor</b> |   |   |           |                |                  |     |      |       |      |
| $R_{th(j-s)I}$  | per IGBT  |   |           | 0,032          | K/W              |     |      |       |      |
| $R_{th(j-s)D}$  | per diode   |   |           | 0,094          | K/W              |     |      |       |      |
| $R_{th(s-a)}$   | per module  |   |           | 0,033          | K/W              |     |      |       |      |
| $Z_{th}$  | $R_i$ (mK/W) (max. values)  |   |           | $\tau_{th}(s)$ |                  |     |      |       |      |
|   | 1   | 2   | 3         | 4              | 1                | 2   | 3    | 4     |      |
| $Z_{th(j-r)I}$  |   | 4   | 25        | 4              | 0                | 1   | 0,13 | 0,001 | 1    |
| $Z_{th(j-r)D}$  |   | 10  | 72        | 11             | 0                | 1   | 0,13 | 0,001 | 1    |
| $Z_{th(r-a)}$   |   | 1,6   | 22        | 7              | 2,4              | 494 | 165  | 20    | 0,03 |



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# SKiiP 832GB120-4D



SKiiP® 2

## 2-pack - integrated intelligent Power System

### 2-pack integrated gate driver

#### SKiiP 832GB120-4D

#### Gate driver features

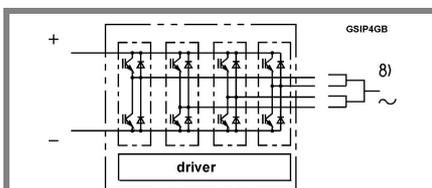
- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 60068-1 (climate) 25/85/56

| Absolute Maximum Ratings |                                       | $T_a = 25^\circ\text{C}$ unless otherwise specified |                   |
|--------------------------|---------------------------------------|---|-------------------|
| Symbol                   | Conditions                            | Values  | Units             |
| $V_{S1}$                 | stabilized 15 V power supply          | 18  | V                 |
| $V_{S2}$                 | unstabilized 24 V power supply        | 30  | V                 |
| $V_{iH}$                 | input signal voltage (high)           | 15 + 0,3  | V                 |
| dv/dt                    | secondary to primary side             | 75  | kV/ $\mu\text{s}$ |
| $V_{isolIO}$             | input / output (AC, r.m.s., 2s )      | 3000  | Vac               |
| $V_{isol12}$             | output 1 / output 2 (AC, r.m.s., 2s ) | 1500  | Vac               |
| $f_{sw}$                 | switching frequency                   | 19  | kHz               |
| $f_{out}$                | output frequency for $I=I_C$ ; sin.   | 1   | kHz               |
| $T_{op}$ ( $T_{stg}$ )   | operating / storage temperature       | - 40 ... + 85                                       | $^\circ\text{C}$  |

| Characteristics |  | $(T_a = 25^\circ\text{C})$          |      |      |                  |
|-----------------|--|-------------------------------------|------|------|------------------|
| Symbol          | Conditions   | min.                                | typ. | max. | Units            |
| $V_{S1}$        | supply voltage stabilized  | 14,4                                | 15   | 15,6 | V                |
| $V_{S2}$        | supply voltage non stabilized  | 20                                  | 24   | 30   | V                |
| $I_{S1}$        | $V_{S1} = 15\text{ V}$   | $290+410*f/f_{max}+1,2*(I_{AC}/A)$  |      |      | mA               |
| $I_{S2}$        | $V_{S2} = 24\text{ V}$   | $220+300*f/f_{max}+0,85*(I_{AC}/A)$ |      |      | mA               |
| $V_{iT+}$       | input threshold voltage (High)   | 12,3                                |      |      | V                |
| $V_{iT-}$       | input threshold voltage (Low)  | 4,6                                 |      |      | V                |
| $R_{IN}$        | input resistance   | 10                                  |      |      | k $\Omega$       |
| $t_{d(on)IO}$   | input-output turn-on propagation time  | 1,5                                 |      |      | $\mu\text{s}$    |
| $t_{d(off)IO}$  | input-output turn-off propagation time   | 1,4                                 |      |      | $\mu\text{s}$    |
| $t_{pERRRESET}$ | error memory reset time  | 9                                   |      |      | $\mu\text{s}$    |
| $t_{TD}$        | top / bottom switch : interlock time   | 3,3                                 |      |      | $\mu\text{s}$    |
| $I_{analogOUT}$ | 8 V corresponds to max. current of 15 V supply voltage (available when supplied with 24 V) | 800                                 |      |      | A                |
| $I_{Vs1outmax}$ | output current at pin 12/14  | 50                                  |      |      | mA               |
| $I_{A0max}$     | output current at pin 12/14  | 5                                   |      |      | mA               |
| $V_{O1}$        | logic low output voltage   | 0,6                                 |      |      | V                |
| $V_{O1H}$       | logic high output voltage  | 30                                  |      |      | V                |
| $I_{TRIPSC}$    | over current trip level ( $I_{analog OUT} = 10\text{ V}$ )                                 | 1000                                |      |      | A                |
| $I_{TRIPLG}$    | ground fault protection  | 120                                 |      |      | A                |
| $T_{tp}$        | over temperature protection  | 110                                 |      |      | $^\circ\text{C}$ |
| $U_{DCTRIIP}$   | trip level of $U_{DC}$ -protection ( $U_{analog OUT} = 9\text{ V}$ ); (option)             | 900                                 |      |      | V                |

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